

NTA4001NT1 Datasheet

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DiGi Electronics Part Number	NTA4001NT1-DG
Manufacturer	onsemi
Manufacturer Product Number	NTA4001NT1
Description	MOSFET N-CH 20V 238MA SC75
Detailed Description	N-Channel 20 V 238mA (Tj) 300mW (Tj) Surface Mo unt SC-75, SOT-416

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
NTA4001NT1	onsemi
Series:	Product Status:
	Obsolete
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
20 V	238mA (Tj)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
2.5V, 4.5V	30hm @ 10mA, 4.5V
Vgs(th) (Max) @ ld:	Vgs (Max):
1.5V @ 100µA	±10V
Input Capacitance (Ciss) (Max) @ Vds:	FET Feature:
20 pF @ 5 V	
Power Dissipation (Max):	Operating Temperature:
300mW (Tj)	-55°C ~ 150°C (TJ)
Mounting Type:	Supplier Device Package:
Surface Mount	SC-75, SOT-416
Package / Case:	Base Product Number:
SC-75, SOT-416	NTA40

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
RoHS non-compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0095	

NTA4001N, NVA4001N

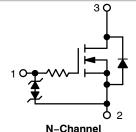
MOSFET – Single, N-Channel, Gate ESD Protection, Small Signal, SC-75



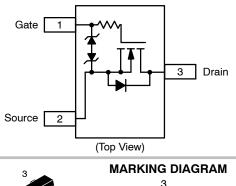
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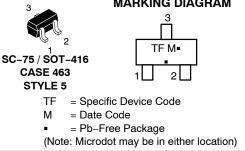
V _{(BR)DSS}	R _{DS(on)} Typ @ V _{GS}	I _D MAX (Note 1)
20 V	1.5 Ω @ 4.5 V	238 mA
20 0	2.2 Ω @ 2.5 V	200 11/1



PIN CONNECTIONS



SC-75 (3-Leads)



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

20 V, 238 mA

Features

- Low Gate Charge for Fast Switching
- Small 1.6 x 1.6 mm Footprint
- ESD Protected Gate
- AEC-Q101 Qualified and PPAP Capable NVA4001N
- These Devices are Pb-Free and are RoHS Compliant

Applications

- Power Management Load Switch
- Level Shift
- Portable Applications such as Cell Phones, Media Players, Digital Cameras, PDA's, Video Games, Hand Held Computers, etc.

MAXIMUM RATINGS (T_J = 25°C unless otherwise stated)

Parameter		Symbol	Value	Unit
Drain-to-Source Voltage		V _{DSS}	20	V
Gate-to-Source Voltage		V _{GS}	±10	V
Continuous Drain Current (Note 1)	Steady State = 25°C	۱ _D	238	mA
Power Dissipation (Note 1)			300	mW
$\label{eq:pulsed Drain Current} Pulsed Drain Current \qquad t_P \le 10 \mu s$		I _{DM}	714	mA
Operating Junction and Storage Temperature		T _J , T _{STG}	–55 to 150	°C
Continuous Source Current (Body Diode)		I _{SD}	238	mA
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)		ΤL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 1)	$R_{\theta JA}$	416	°C/W

1. Surface-mounted on FR4 board using 1 in sq. pad size (Cu area = 1.127 in sq. [1 oz] including traces).

NTA4001NT1 onsemi MOSFET N-CH 20V 238MA SC75

NTA4001N, NVA4001N

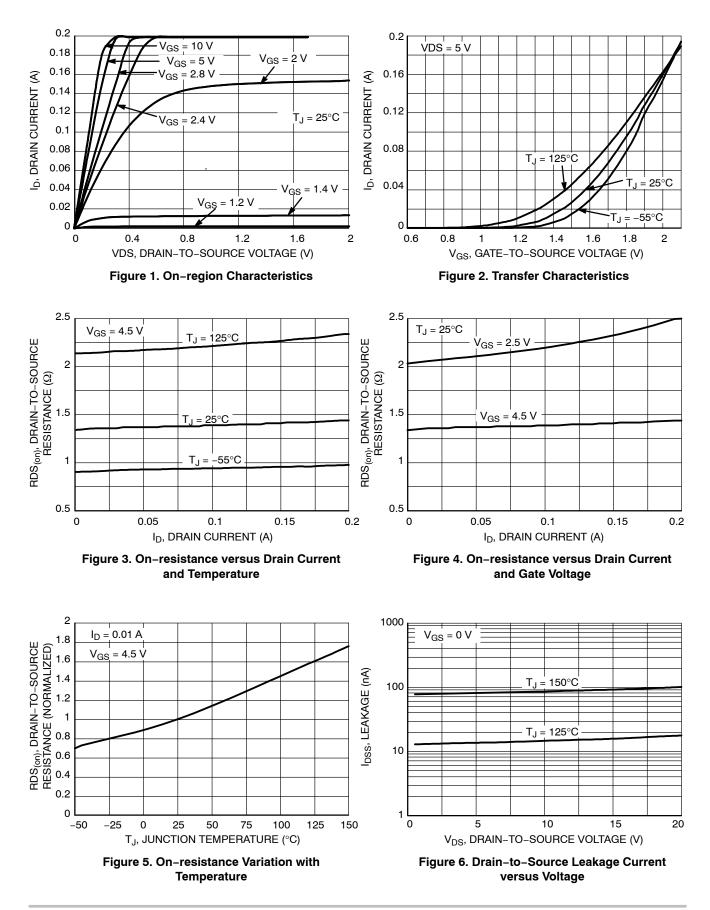
ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I_D = 100 μ A	20			V
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 \text{ V}, \text{ V}_{DS} = 20 \text{ V}$			1.0	μA
Gate-to-Source Leakage Current	I _{GSS}	V_{DS} = 0 V, V_{GS} = ±10 V			±100	μA
ON CHARACTERISTICS (Note 2)						
Gate Threshold Voltage	V _{GS(TH)}	V_{DS} = 3 V, I_D = 100 μ A	0.5	1.0	1.5	V
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 10 mA		1.5	3.0	
		V _{GS} = 2.5 V, I _D = 10 mA		2.2	3.5	Ω
Forward Transconductance	9 FS	V _{DS} = 3 V, I _D = 10 mA		80		mS
CAPACITANCES						
Input Capacitance	C _{ISS}			11.5	20	
Output Capacitance	C _{OSS}	V _{DS} = 5 V, f = 1 MHz, V _{GS} = 0 V		10	15	pF
Reverse Transfer Capacitance	C _{RSS}	- • • • • •		3.5	6.0	1
SWITCHING CHARACTERISTICS (Note 3)			-	-		-
Turn-On Delay Time	t _{d(ON)}			13		ns
Rise Time	t _r	V _{GS} = 4.5 V, V _{DS} = 5 V,		15		
Turn-Off Delay Time	t _{d(OFF)}	$I_D = 10 \text{ mA}, R_G = 10 \Omega$		98		ns
Fall Time	t _f			60		1
DRAIN-SOURCE DIODE CHARACTERISTICS	•		•	•	•	
Forward Diode Voltage	V _{SD}	V _{GS} = 0 V, I _S = 10 mA		0.66	0.8	V

Pulse rest. pulse width ≤ 300 µs, duty cycle ≤ 2 /s.
Switching characteristics are independent of operating junction temperatures.

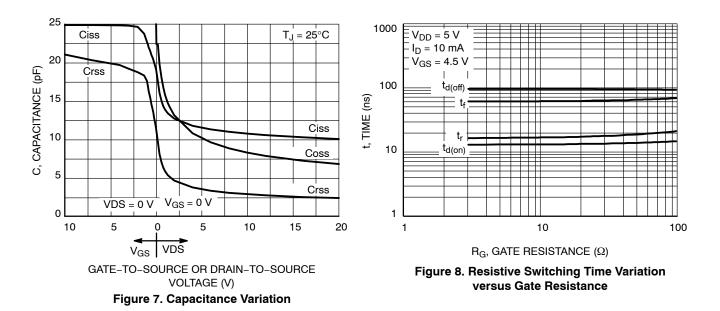
NTA4001N, NVA4001N

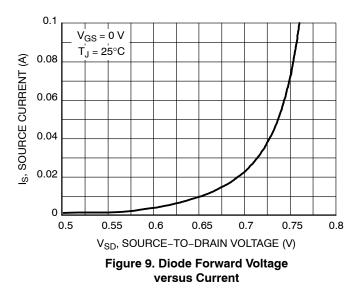
TYPICAL PERFORMANCE CURVES



NTA4001N, NVA4001N

TYPICAL PERFORMANCE CURVES





ORDERING INFORMATION

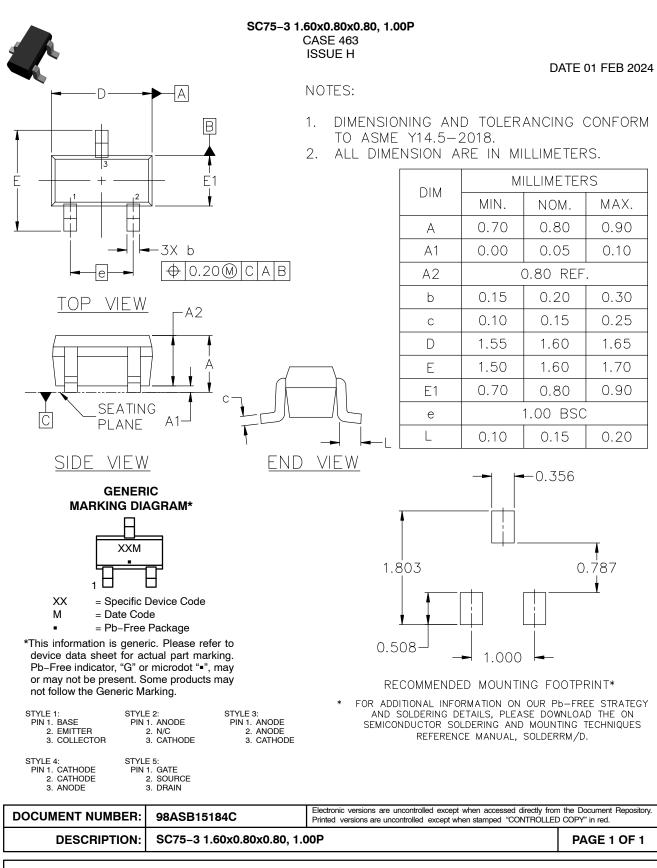
Order Number	Package	Shipping [†]
NTA4001NT1G	SC-75 (Pb-Free)	3000 / Tape & Reel
NVA4001NT1G	SC-75 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS



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